



Rev.01 - 30 August 2022

**Product data sheet** 

### 1. General description

Dual common cathode power Schottky diode designed for high frequency switched mode power supplies in a TO220F "full pack" plastic package.



## 2. Features and benefits

- Trench structure
- High junction temperature up to 150°C
- · Low forward voltage drop, negligible switching losses
- High efficiency

## 3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- · Switched mode power supply rectifier

## 4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Notes	Values		<b>;</b>	Unit
Absolute	maximum rating						
$V_{\text{RRM}}$	repetitive peak reverse voltage				45		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; per diode; <u>Fig. 1; Fig. 2; Fig. 3</u>			15		A
I <sub>O(AV)</sub>	average output current	$\delta$ = 0.5 ; square-wave pulse; both diodes conducting		30			А
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static characteristics							
V <sub>F</sub>	forward voltage	$I_{F}$ = 15 A; $T_{j}$ = 25 °C; per diode; <u>Fig. 6</u>		-	0.50	0.60	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 45 V; T <sub>j</sub> = 25 °C; per diode; <u>Fig. 7; Fig. 8</u>		-	40	100	μA

# **5. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1	mb	
2	К	cathode		
3	A2	anode 2		K sym125
mb	n.c.	mounting base; isolated		<i></i>

# 6. Ordering information

Table 3. Ordering information									
	Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
		name		method	quantity	version	issue date		
	WN3S30H45CX	TO220F	WN3S30H45CXQ	Tube	50	SOT186A	14-Nov-2013		

## 7. Marking

Table 4. Marking codes	
Type number	Marking codes
WN3S30H45CX	WN3S30 H45CX

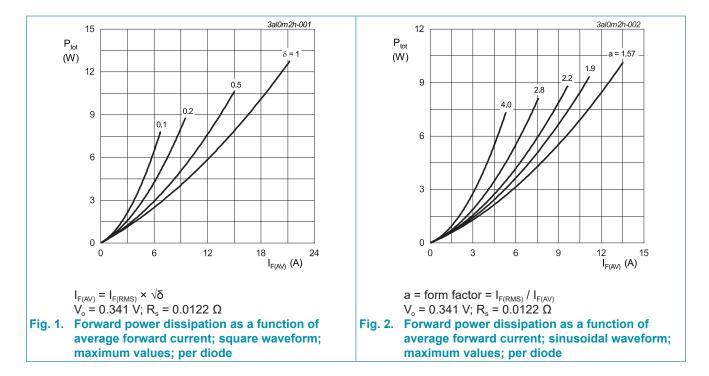
## 8. Limiting values

### Table 5. Limiting values

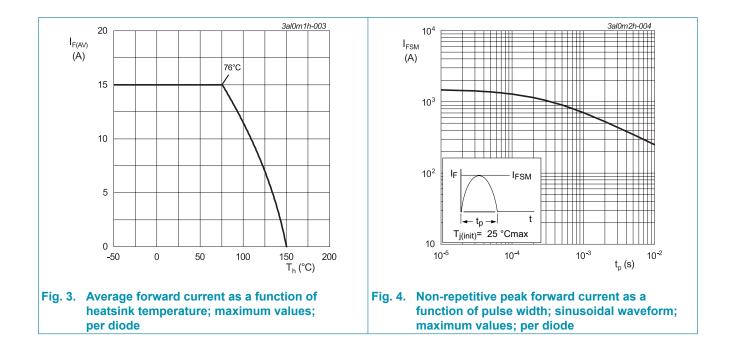
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
$V_{\text{RRM}}$	repetitive peak reverse voltage			45	V
$V_{\text{RWM}}$	crest working reverse voltage			45	V
V <sub>R</sub>	reverse voltage	DC		45	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5 ; square-wave pulse; per diode; Fig. 1; Fig. 2; Fig. 3		15	A
I <sub>O(AV)</sub>	average output current	$\delta$ = 0.5 ; square-wave pulse; both diodes conducting		30	A
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode; Fig. 4		250	A
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		275	A
T <sub>stg</sub>	storage temperature			-40 to 150	°C
T <sub>j</sub>	junction temperature		[1]	-40 to 150	°C

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient:  $dP_{tot}/dT_j < 1/R_{th(j-a)}$ 

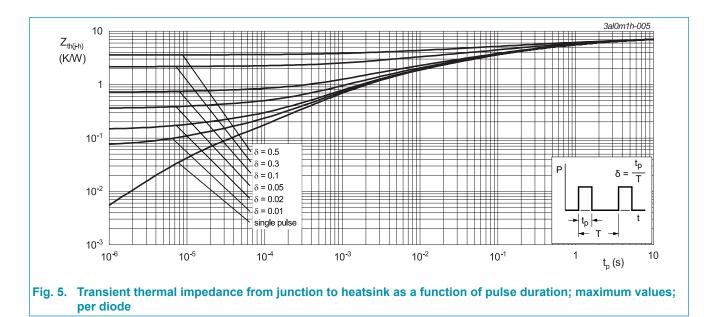


WN3S30H45CX Dual power Schottky diode



## 9. Thermal characteristics

Table 6. Thermal characteristics								
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit	
$R_{\text{th(j-h)}}$	thermal resistance from junction to	with heatsink compound; per diode; Fig. 5		-	-	7	K/W	
	heatsink	with heatsink compound; both diodes conducting		-	-	4.8	K/W	
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	65	-	K/W	



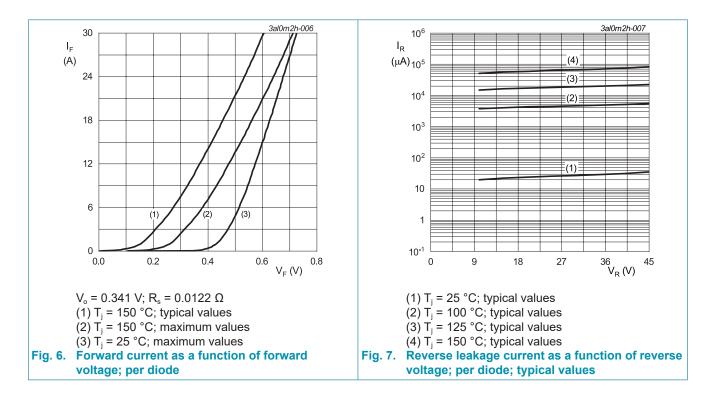
## 10. Isolation characteristics

### Table 7. Isolation characteristics

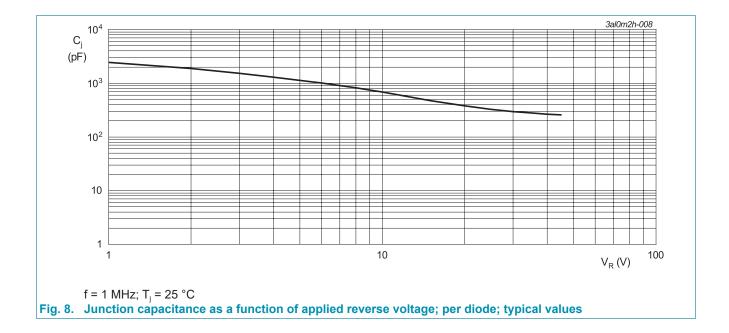
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz $\leq$ f $\leq$ 60 Hz; T <sub>h</sub> = 25 °C; RH $\leq$ 65 %		-	-	2500	V

**11. Characteristics** 

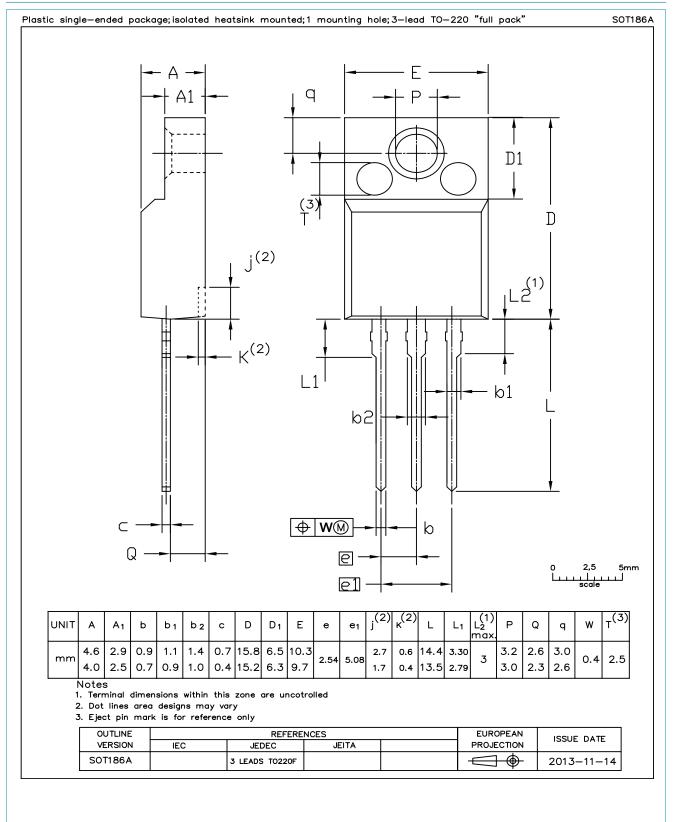
Table 8. Cl	naracteristics						
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 15 A; T <sub>j</sub> = 25 °C; per diode; <u>Fig. 6</u>		-	0.50	0.60	V
		$I_{F} = 15 \text{ A}; T_{j} = 125 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.44	-	V
		$I_F = 5 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.40	-	V
		$I_{F} = 5 \text{ A}; T_{j} = 125 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.29	-	V
l <sub>R</sub>	reverse current	V <sub>R</sub> = 45 V; T <sub>j</sub> = 25 °C; per diode; Fig. 7; Fig. 8		-	40	100	μA
		V <sub>R</sub> = 45 V; T <sub>j</sub> = 125 °C; per diode; <u>Fig. 7; Fig. 8</u>		-	25	75	mA



**Dual power Schottky diode** 



## 12. Package outline



### **Dual power Schottky diode**

## 13. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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